

Description

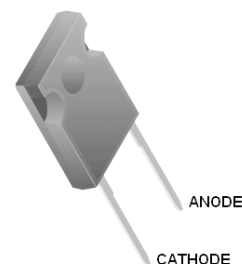
This device is an ultrafast diode with soft recovery characteristics ($t_{rr} < 45\text{ns}$). It is intended for use as a freewheeling /clamping diode and rectifier in a variety of high frequency switching power supplies and other power switching applications. It has low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Features

- Ultrafast with Soft Recovery <45ns
- Reverse Voltage600V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose



TO-247



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	600	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
Average Rectified Forward Current($T_C = 110^\circ\text{C}$, Duty=0.5)	$I_{F(AV)}$	60	A
Repetitive Peak Surge Current($T_C = 110^\circ\text{C}$, Duty=0.5)	I_{FRM}	90	
Nonrepetitive Peak Surge Current($T_J = 45^\circ\text{C}$, 8.3ms)	I_{FSM}	600	
Storage Temperature Range	T_{STG}	-40-150	$^\circ\text{C}$
Junction Temperature	T_J	-40-150	$^\circ\text{C}$
Junction to Ambient thermal resistance	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Junction to Case thermal resistance	$R_{\theta JC}$	2.0	$^\circ\text{C/W}$

Electrical Characteristics ($T_C = 25^\circ\text{C}$)

Parameter	Symbol
Instantaneous forward voltage ($p_w = 300\mu\text{s}$, $D = 2\%$)	V_F
Instantaneous reverse current	I_R
Reverse recovery time (Figure 6), summation of $t_a + t_b$	t_{rr}
Reverse recovery Charge	Q_{rr}
Max. Reverse recovery Current	I_{RRM}
Junction to free air thermal resistance	$R_{\theta JA}$
Pulse width	p_w
Duty cycle	D

Electrical Specifications ($T_C = 25^\circ\text{C}$)

Symbol	Test Conditions	Min.	Typ.	Max.	Unit
V_F	$I_F=60\text{A}, T_{AIC}=25^\circ\text{C}$		1.3	1.7	V
	$I_F=60\text{A}, T_C=125^\circ\text{C}$		1.1		V
I_R	$V_R=600\text{V}, T_C=25^\circ\text{C}$			50	μA
	$V_R=600\text{V}, T_C=125^\circ\text{C}$			250	μA
t_{rr}	$I_F=1\text{A}, V_R=30\text{V}, di/dt=200\text{A}/\mu\text{s}$		45		ns
	$I_F=60\text{A}, V_R=300\text{V}, di/dt=200\text{A}/\mu\text{s}, T_C=25^\circ\text{C}$		85		ns
	$I_F=60\text{A}, V_R=300\text{V}, di/dt=200\text{A}/\mu\text{s}, T_C=125^\circ\text{C}$		220		ns
Q_{rr}	$I_F=60\text{A}, V_R=300\text{V}, di/dt=200\text{A}/\mu\text{s}, T_C=125^\circ\text{C}$		2400		nC
I_{RRM}	$I_F=60\text{A}, V_R=300\text{V}, di/dt=200\text{A}/\mu\text{s}, T_C=125^\circ\text{C}$		22		A

Typical Performance Curves

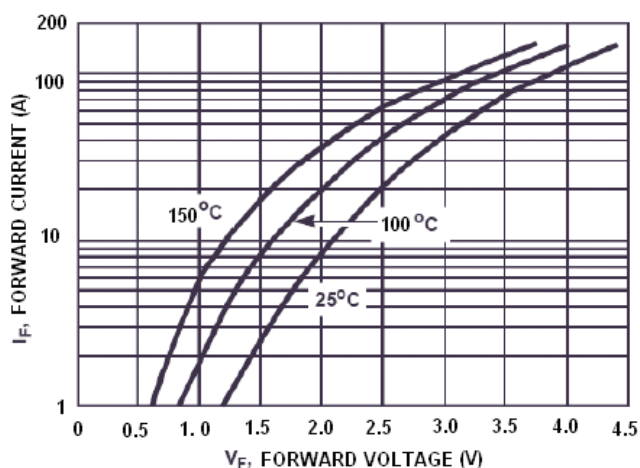


FIGURE1. FORWARD CURRENT vs FORWARD VOLTAGE

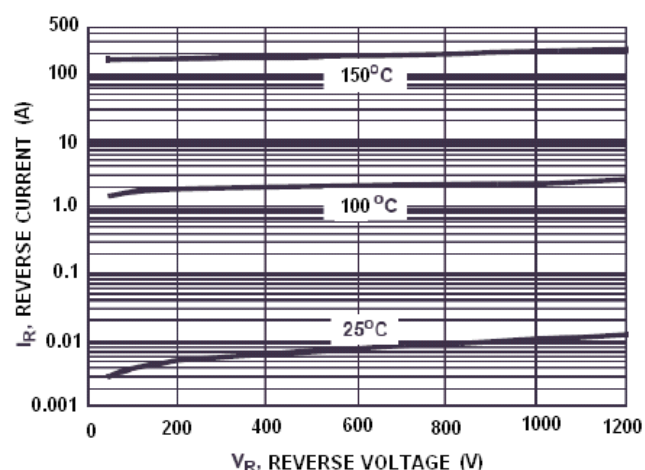


FIGURE2. REVERSE CURRENT vs REVERSE VOLTAGE

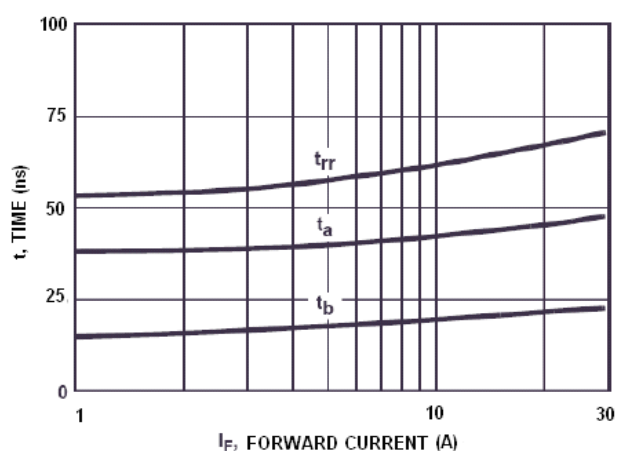


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

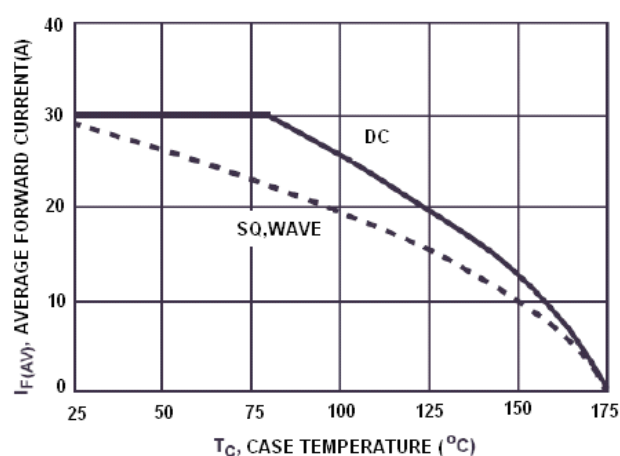


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

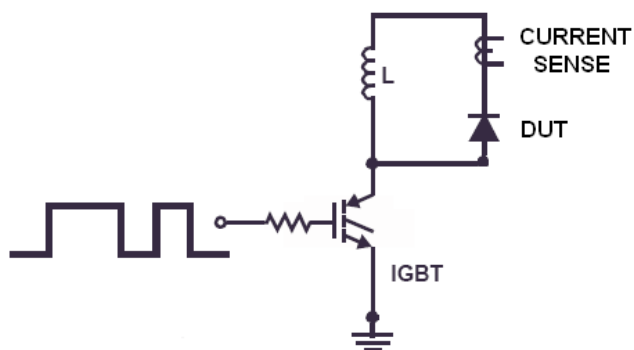


FIGURE 5. t_{rr} TEST CIRCUIT

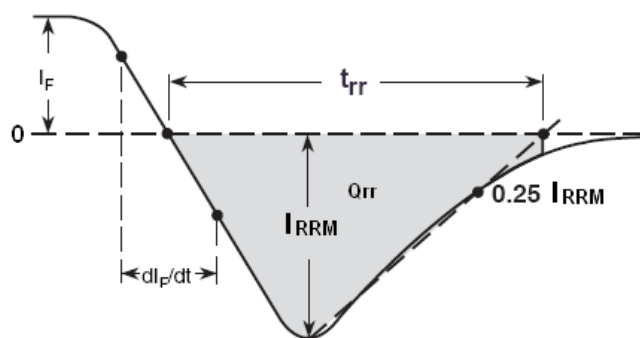
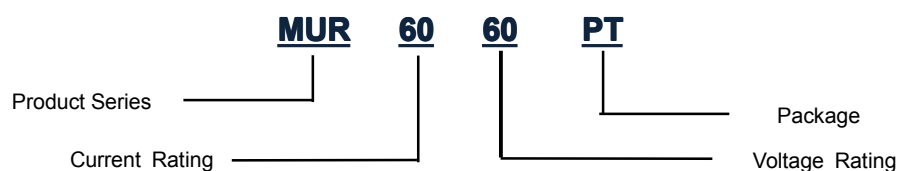


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

Marking and Order Information

Part Number System



Order Information

Device	Package	Net Weight	Carrier	Quantity	HSF Status
MUR6060PT	TO-247	5.26g	Tube & Box	1,200 pcs/box	Lead Free

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